ES3A THRU ES3J

SURFACE MOUNT FAST ULTRAFAST RECTIFIER

VOLTAGE: 50 TO 600V CURRENT: 3.0A



FEATURE

Ideal for surface mount pick and place application

Low profile package

Built-in strain relief

High surge capability

High temperature soldering guaranteed

260 $^{\circ}\text{C}/\text{10sec/at terminals}$

Glass passivated chip

Ultrafast recovery time for high efficiency

MECHANICAL DATA

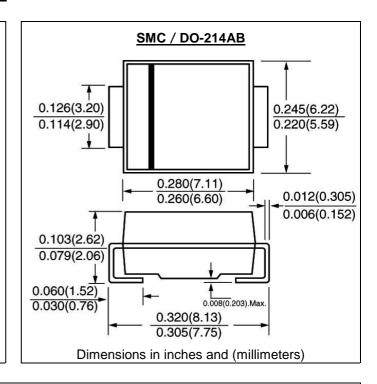
Terminal: Solder plated, solderable per MIL-STD-750,

Method 2026

Case: JEDEC DO-214AB molded plastic body over

passivated chip

Polarity: color band denotes cathode



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half-wave, 60HZ, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

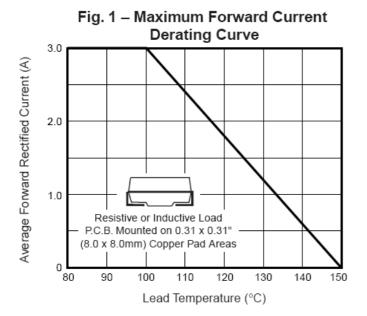
	SYMBOL	ES3A	ES3B	ES3C	ES3D	ES3G	ES3J	units
Maximum Recurrent Peak Reverse Voltage	Vrrm	50	100	150	200	400	600	V
Maximum RMS Voltage	Vrms	35	70	105	140	280	420	V
Maximum DC blocking Voltage	Vdc	50	100	150	200	400	600	V
Maximum Average Forward Rectified at T _L =100°C	If(av)	3.0						Α
Peak Forward Surge Current 8.3ms single half sine- wave superimposed on rated load	Ifsm	100.0						Α
Maximum Instantaneous Forward Voltage at rated forward current 3.0A	Vf	0.90				1.25	1.7	V
Maximum DC Reverse Current Ta =25°C at rated DC blocking voltage Ta =100°C	lr	10.0 500.0						μA
Maximum Reverse Recovery Time (Note1)	Trr	20			25	35	nS	
Typical Junction Capacitance (Note 2)	Cj	45.0						pF
Typical Thermal Resistance (Note 3)	Rth(jl)	12.0						°C/W
Storage and Operating Junction Temperature	Tstg, Tj	-55 to +150						$^{\circ}$

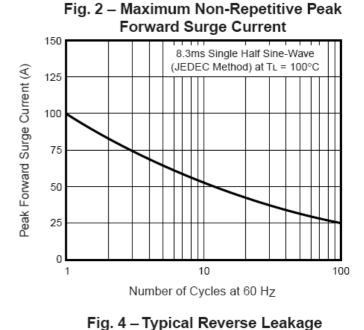
Note:

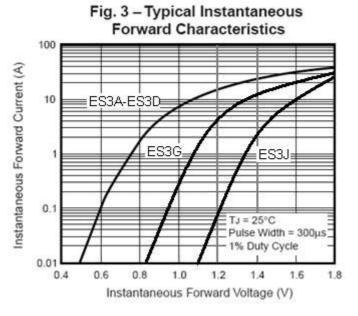
- 1. Reverse Recovery Condition If =0.5A, Ir =1.0A, Irr =0.25A
- 2. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc
- 3. Thermal Resistance from Junction to terminal mounted on 5×5mm copper pad area

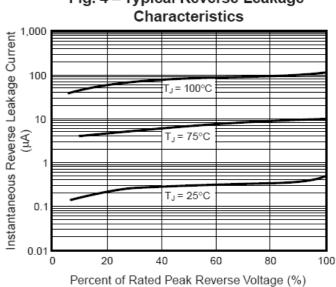
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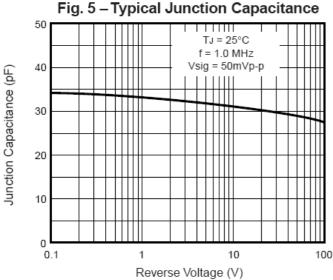
RATINGS AND CHARACTERISTIC CURVES ES3A THRU ES3J











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